## Features

- High voltage capability
- Very high switching speed


## Applications

Four lamp electronic ballast for:
■ 120 V mains in push-pull configuration

- 277 V mains in half bridge current feed configuration


## Description

This is a high voltage fast switching NPN power transistor manufactured in multi epitaxial planar technology. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining a wide RBSOA.
Thanks to an increased intermediate layer, it has an intrinsic ruggedness which enables the transistor to withstand a high collector current level during breakdown condition, without using the Transil ${ }^{\text {TM }}$ protection usually necessary in typical converters for lamp ballast.


Figure 1. Internal schematic diagram


Table 1. Device summary

| Order codes | Marking | Package | Packaging |
| :---: | :---: | :---: | :---: |
| BUL1102E | BUL1102E | TO-220 | Tube |
| BUL1102EFP | BUL1102EFP | TO-220FP | Tube |

## 1 <br> Absolute maximum ratings

Table 2. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CES}}$ | Collector-emitter voltage $\left(\mathrm{V}_{\mathrm{BE}}=0\right)$ | 1100 | V |
| $\mathrm{~V}_{\mathrm{CEO}}$ | Collector-emitter voltage $\left(\mathrm{I}_{\mathrm{B}}=0\right)$ | 450 | V |
| $\mathrm{~V}_{\text {EBO }}$ | Emitter-base voltage $\left(\mathrm{I}_{\mathrm{C}}=0\right)$ | 12 | V |
| $\mathrm{I}_{\mathrm{C}}$ | Collector current | 4 | A |
| $\mathrm{I}_{\mathrm{CM}}$ | Collector peak current $\left(\mathrm{t}_{\mathrm{P}}<5 \mathrm{~ms}\right)$ | 8 | A |
| $\mathrm{I}_{\mathrm{B}}$ | Base current | 2 | A |
| $\mathrm{I}_{\mathrm{BM}}$ | Base peak current ( $\mathrm{t}_{\mathrm{P}}<5$ ms $)$ | 4 | A |
| $\mathrm{P}_{\mathrm{TOT}}$ | BUL1102E total dissipation at $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ <br> BUL1102EFP total dissipation at $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 70 | W |
| $\mathrm{~V}_{\text {ISO }}$ | BUL1102EFP insolation withstand voltage $(\mathrm{RMS})$ from <br> all three leads to external heatsink | 1500 | V |
| $\mathrm{~T}_{\mathrm{STG}}$ | Storage temperature | -65 to 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{J}}$ | Max. operating junction temperature | 150 | ${ }^{\circ} \mathrm{C}$ |

Table 3. Thermal data

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{R}_{\text {thJC }}$ | BUL1203E thermal resistance junction-case | 1.8 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  | BUL1203EFP thermal resistance junction-case | 4.2 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## 2 Electrical characteristics

$\left(T_{J}=25^{\circ} \mathrm{C}\right.$; unless otherwise specified)

Table 4. Electrical characteristics

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $I_{\text {ces }}$ | Collector cut-off current $\left(\mathrm{V}_{\mathrm{BE}}=0\right)$ | $\mathrm{V}_{\mathrm{CE}}=1100 \mathrm{~V}$ |  |  | 100 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {ebo }}$ | Emitter cut-off current $\left(I_{C}=0\right)$ | $\mathrm{V}_{\mathrm{EB}}=12 \mathrm{~V}$ |  |  | 1 | mA |
| $\mathrm{V}_{\text {CEO(sus) }}{ }^{(1)}$ | Collector-emitter sustaining voltage $\left(\mathrm{I}_{\mathrm{B}}=0\right)$ | $\mathrm{I}_{\mathrm{C}}=100 \mathrm{~mA}$ | 450 |  |  | V |
| $\mathrm{V}_{\mathrm{CE} \text { (sat) }}{ }^{(1)}$ | Collector-emitter saturation voltage | $\mathrm{I}_{\mathrm{C}}=2 \mathrm{~A} \quad \mathrm{I}_{\mathrm{B}}=400 \mathrm{~mA}$ |  |  | 1.5 | V |
| $\mathrm{V}_{\mathrm{BE} \text { (sat) }}{ }^{(1)}$ | Base-emitter saturation voltage | $\mathrm{I}_{C}=2 \mathrm{~A} \quad \mathrm{I}_{\mathrm{B}}=400 \mathrm{~mA}$ |  |  | 1.5 | V |
| $\mathrm{h}_{\text {FE }}{ }^{(1)}$ | DC current gain | $\begin{array}{ll} \mathrm{I}_{\mathrm{C}}=250 \mathrm{~mA} & \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V} \\ \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A}, & \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V} \\ \text { for BUL1102E } & \\ \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A} & \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V} \\ \text { for BUL1102EFP } \end{array}$ | $35$ <br> 12 $12$ |  | $70$ <br> 20 $23$ |  |
| $\begin{aligned} & \mathrm{t}_{\mathrm{s}} \\ & \mathrm{t}_{\mathrm{f}} \end{aligned}$ | Resistive load Storage time Fall time | $\begin{array}{\|ll} \hline \mathrm{I}_{\mathrm{C}}=2.5 \mathrm{~A} & \mathrm{~V}_{\mathrm{CC}}=250 \mathrm{~V} \\ \mathrm{I}_{\mathrm{B} 1}=0.5 \mathrm{~A} & \mathrm{I}_{\mathrm{B} 2}=1 \mathrm{~A} \\ \mathrm{~T}_{\mathrm{P}}=30 \mu \mathrm{~s} \text { (see } & \text { Figure 14) } \end{array}$ |  |  | $\begin{aligned} & 2.5 \\ & 300 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{s} \\ & \mathrm{~ns} \end{aligned}$ |
| $\mathrm{E}_{\text {ar }}$ | Avalanche energy | $\begin{aligned} & \mathrm{L}=2 \mathrm{mH} \quad \mathrm{C}=1.8 \mathrm{nF} \\ & \mathrm{I}_{\mathrm{BR}} \leq 2.5 \mathrm{~A} \quad 25^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{C}}<125^{\circ} \mathrm{C} \\ & \text { (see Figure 12) } \end{aligned}$ | 6 |  |  | mJ |

1. Pulse test: pulse duration $\leq 300 \mu \mathrm{~s}$, duty cycle $\leq 2 \%$.

### 2.1 Typical characteristics (curves)



Figure 3. BUL1102EFP safe operating area
Figure 3. BUL1102EFP safe operating area

Figure 2. BUL1102E safe operating area


Figure 4. Derating curve


Figure 6. $D C$ current gain $\left(V_{C E}=5 \mathrm{~V}\right)$


Figure 5. DC current gain ( $\mathrm{V}_{\mathrm{CE}}=1 \mathrm{~V}$ )
(VCE =1V)


Figure 7. Collector emitter saturation voltage


Figure 8. Base emitter saturation voltage
Figure 9. Resistive load switching times


Figure 10. Inductive load switching times


Figure 11. Reverse biased SOA


Figure 12. Energy rating test circuit


Figure 13. Inductive load switching test circuit


Figure 14. Resistive load switching test circuit


## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK ${ }^{\circledR}$ packages, depending on their level of environmental compliance. ECOPACK ${ }^{\circledR}$ specifications, grade definitions and product status are available at: www.st.com. ECOPACK ${ }^{\circledR}$ is an ST trademark.

Table 5. TO-220 type A mechanical data

| Dim. | mm |  | Max. |
| :---: | :---: | :---: | :---: |
|  | Min. | Typ. | 4.60 |
| A | 4.40 |  | 0.88 |
| b | 0.61 |  | 1.70 |
| b1 | 1.14 |  | 0.70 |
| c | 0.48 |  | 15.75 |
| D | 15.25 |  | 10.40 |
| D1 |  |  | 2.70 |
| E | 10 |  | 5.15 |
| e | 2.40 |  | 1.32 |
| e1 | 1.95 |  | 6.60 |
| F | 6.20 |  | 2.72 |
| H1 | 2.40 |  | 14 |
| J1 | 13 |  | 3.93 |
| L | 3.50 |  |  |
| L1 |  |  | 3.80 |
| L20 |  |  | 28.90 |
| L30 |  |  |  |
| ØP | 2.75 |  |  |
| Q |  |  |  |

Figure 15. TO-220 type A drawing


Table 6. TO-220FP mechanical data

| Dim. | mm |  |  |
| :---: | :---: | :---: | :---: |
|  | Min. | Typ. | Max. |
| A | 4.4 |  | 4.6 |
| B | 2.5 |  | 2.7 |
| D | 2.5 |  | 2.75 |
| E | 0.45 |  | 0.7 |
| F | 0.75 |  | 1 |
| F1 | 1.15 |  | 1.70 |
| F2 | 1.15 |  | 1.70 |
| G | 4.95 |  | 5.2 |
| G1 | 2.4 |  | 2.7 |
| H | 10 |  | 10.4 |
| L2 | 28.6 |  | 30.6 |
| L3 | 9.8 |  | 10.6 |
| L4 | 2.9 |  | 3.6 |
| L5 | 15.9 |  | 16.4 |
| L6 | 9 |  | 9.3 |
| L7 | 3 |  | 3.2 |
| Dia |  |  |  |

Figure 16. TO-220FP drawing


## 4 Revision history

Table 7. Document revision history

| Date | Revision | Changes |
| :---: | :---: | :--- |
| 17-Jan-2008 | 3 |  |
| 24-Mar-2011 | 4 | Inserted BUL1102EFP order code in TO-220FP package |
| 15-Feb-2012 | 5 | DC current gain values in Table 4 modified |

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